Low-power D-type flip-flop with reset; positive-edge trigger Rev. 6 — 2 April 2021 Product data sheet

1. General description

The 74AUP1G175 provides a low-power, low-voltage positive-edge triggered D-type flip-flop with individual data (D) input, clock (CP) input, master reset (\overline{MR}) input, and Q output. The master reset (\overline{MR}) is an asynchronous active LOW input and operates independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition, for predictable operation.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

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This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

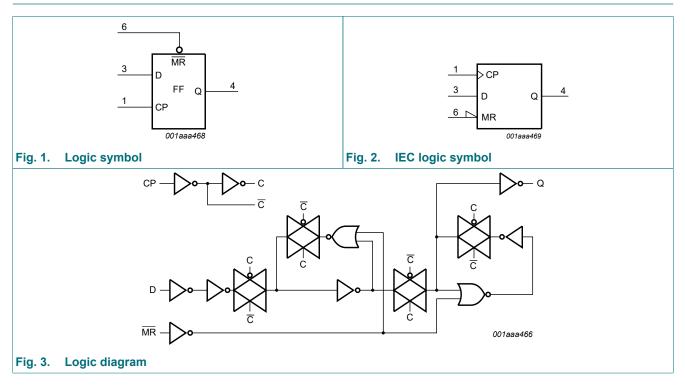
Type number	Package								
	Temperature range	Name	Description	Version					
74AUP1G175GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363					
74AUP1G175GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					
74AUP1G175GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115					
74AUP1G175GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202					

4. Marking

Table 2. Marking					
Type number	Marking code [1]				
74AUP1G175GW	aT				
74AUP1G175GM	aT				
74AUP1G175GN	aT				
74AUP1G175GS	aT				

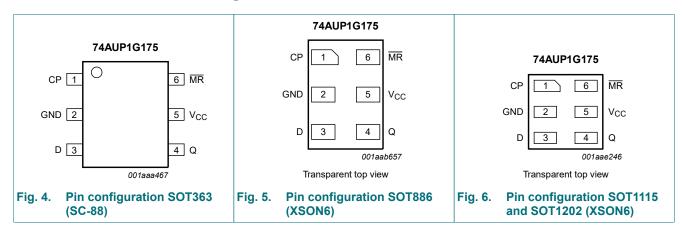
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



74AUP1G175

6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description						
Symbol	Pin	Description				
СР	1	clock input (LOW-to-HIGH, edge-triggered)				
GND	2	ground (0 V)				
D	3	data input				
Q	4	flip-flop output				
V _{CC}	5	supply voltage				
MR	6	master reset input (active LOW)				

7. Functional description

Table 4. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition; L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;

 \uparrow = LOW-to-HIGH CP transition; X = don't care.

Operating mode	Input	nput					
	MR	СР	D	Q			
Reset (clear)	L	Х	Х	L			
Load '1'	Н	1	h	Н			
Load '0'	Н	1	l	L			

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363 (SC-88) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C. For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	1	11		1	1
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
∆I _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
∆I _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF

Low-power D-type	e flip-flop with reset;	positive-edge trigger
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C		<u> </u>			
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
OFF	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$.6 V; ±0.		±0.6	μA
lcc	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +125 °C		<u> </u>		-	
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	or V_{CC} ; $I_0 = 0 A$; 1.		1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	rameter Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F								1	
t _{pd}	propagation	CP to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	21.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	5.9	11.7	2.2	11.9	2.2	12.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.0	4.1	6.8	1.8	7.3	1.8	7.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.6	3.3	5.4	1.3	5.9	1.3	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.3	2.5	3.6	1.1	4.0	1.1	4.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.2	2.1	2.9	1.0	3.3	1.0	3.5	ns
		$\overline{\text{MR}}$ to Q; see <u>Fig. 8</u> [2]								
		V _{CC} = 0.8 V	-	17.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	5.2	9.7	2.2	10.0	2.2	12.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	3.8	5.2	2.1	6.4	2.1	6.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.1	4.9	1.7	5.4	1.7	5.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	3.6	1.5	4.0	1.5	4.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.4	3.1	1.3	3.3	1.3	3.6	ns
f _{max}	maximum	CP; see <u>Fig. 7</u>								
	frequency	V _{CC} = 0.8 V	-	50	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	200	-	170	-	170	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	345	-	310	-	310	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	435	-	400	-	400	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	550	-	490	-	490	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	615	-	550	-	550	-	MHz

Low-power D-type	e flip-flop with	reset; positive	e-edge trigger
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Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 10	pF									
t _{pd}	propagation	CP to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	24.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.8	13.3	2.4	13.6	2.4	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.8	7.9	2.0	8.4	2.0	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.9	6.1	1.8	6.6	1.8	6.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.0	4.3	1.5	4.7	1.5	5.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.7	3.6	1.3	4.0	1.3	4.2	ns
		MR to Q; see <u>Fig. 8</u> [2]								
		V _{CC} = 0.8 V	-	21.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.2	11.5	2.6	11.7	2.6	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.4	6.1	2.4	7.6	2.4	7.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	3.7	5.7	2.2	6.3	2.2	6.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.3	1.9	4.7	1.9	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.0	3.9	1.8	4.1	1.8	4.3	ns
f _{max}	maximum	CP; see <u>Fig. 7</u>								
	frequency	V _{CC} = 0.8 V	-	50	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	190	-	150	-	150	-	MHz
		V _{CC} = 1.4 V to 1.6 V		-	320	-	280	-	280	-
		V _{CC} = 1.65 V to 1.95 V	-	420	-	310	-	310	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	485	-	370	-	370	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	550	-	410	-	410	-	MHz

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 15	pF					1			1	1
t _{pd}	propagation	CP to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	28.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.6	14.8	2.8	15.2	2.8	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.7	5.3	8.7	2.3	9.4	2.3	9.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.4	6.8	2.1	7.4	2.1	7.9	ns
		V_{CC} = 2.3 V to 2.7 V	2.1	3.5	5.0	1.9	5.3	1.9	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.1	4.3	1.7	4.7	1.7	4.9	ns
		MR to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	24.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.0	13.2	2.9	13.5	2.9	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.0	6.8	2.6	8.6	2.6	9.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.3	6.5	2.5	7.2	2.5	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	3.7	5.0	2.2	5.4	2.2	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	3.5	4.4	2.1	4.8	2.1	5.0	ns
f _{max}	maximum	CP; see <u>Fig. 7</u>								
	frequency	V _{CC} = 0.8 V	-	50	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	180	-	120	-	120	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	300	-	190	-	190	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	405	-	240	-	240	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	420	-	300	-	300	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	480	-	320	-	320	-	MHz

Low-power D-type flip-flop with reset; positive-edge trigger

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	C -40 °C to +125 °C		Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	
C _L = 30	pF			1		1		I	1	1
t _{pd} propagation		CP to Q; see Fig. 7 [2]								
	delay	V _{CC} = 0.8 V	-	38.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	9.8	19.5	3.4	20.6	3.4	21.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.3	6.9	11.2	3.2	12.4	3.2	13.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	5.7	8.8	2.9	9.6	2.9	10.2	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	4.6	6.4	2.6	6.9	2.6	7.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	4.2	5.7	2.5	6.5	2.5	6.9	ns
		MR to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	35.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	9.3	18.0	3.7	18.6	3.7	19.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.9	6.6	8.9	3.6	11.6	3.6	12.2	ns
		V _{CC} = 1.65 V to 1.95 V	3.6	5.6	8.6	3.4	9.6	3.4	9.7	ns
		V _{CC} = 2.3 V to 2.7 V	3.5	4.8	6.4	2.9	7.2	2.9	7.2	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	4.6	5.7	3.1	6.4	3.1	6.9	ns
f _{max}	maximum	CP; see Fig. 7								
	frequency	V _{CC} = 0.8 V	-	35	-	-	-	-	-	MHz
		V _{CC} = 1.1 V to 1.3 V	-	130	-	70	-	70	-	MHz
		V _{CC} = 1.4 V to 1.6 V	-	200	-	120	-	120	-	MHz
		V _{CC} = 1.65 V to 1.95 V	-	240	-	150	-	150	-	MHz
		V _{CC} = 2.3 V to 2.7 V	-	275	-	190	-	190	-	MHz
		V _{CC} = 3.0 V to 3.6 V	-	300	-	200	-	200	-	MHz
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF		1		1	1			1
t _W	pulse width	CP; HIGH or LOW; see <u>Fig. 7</u>								
		V _{CC} = 0.8 V	-	5.25	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	1.6	-	1.5	-	1.5	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	1.0	-	0.9	-	0.9	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.75	-	0.7	-	0.7	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.6	-	0.4	-	0.4	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.55	-	0.4	-	0.4	-	ns
		MR; LOW; see Fig. 8								
		V _{CC} = 0.8 V	-	9.0	-	_	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	3.0	-	4.9	-	4.9	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	1.75	-	2.5	-	2.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	1.35	-	1.8	-	1.8	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.9	-	1.1	-	1.1	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.8	-	0.8	-	0.8	-	ns

Low-power D-type flip-flop with reset; positive-edge trigger

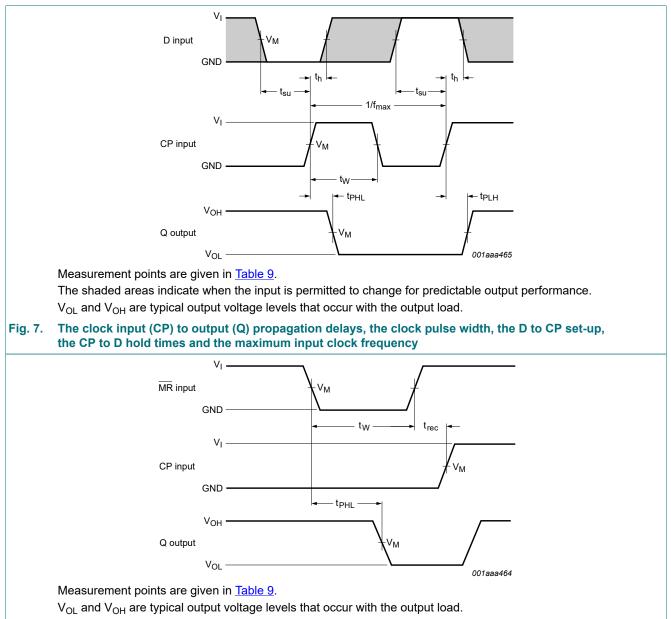
Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1] Max		Min	Мах	Min	Max	
t _{rec}	recovery	MR; see <u>Fig. 8</u>								
	time	V _{CC} = 0.8 V	-	-	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-1.1	-	-1.2	-	-1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-2.0	-	-0.8	-	-0.8	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.5	-	-0.7	-	-0.7	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.9	-	-0.4	-	-0.4	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-1.0	-	-0.2	-	-0.2	-	ns
t _{su(H)}	set-up time	D to CP; see Fig. 7								
	HIGH	V _{CC} = 0.8 V	-	-	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.5	-	1.2	-	1.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.4	-	0.8	-	0.8	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.3	-	0.6	-	0.6	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.3	-	0.5	-	0.5	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.2	-	0.5	-	0.5	-	ns
t _{su(L)}	set-up time	D to CP; see Fig. 7								
	LOW	V _{CC} = 0.8 V	-	-	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.8	-	1.7	-	1.7	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.6	-	1.1	-	1.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	0.9	-	0.9	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.4	-	0.9	-	0.9	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.5	-	0.9	-	0.9	-	ns
t _h	hold time	D to CP; see <u>Fig. 7</u>								
		V _{CC} = 0.8 V	-	-	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-0.7	-	0.2	-	0.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.5	-	0	-	0	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.5	-	0	-	0	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	-0.3	-	0	-	0	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.4	-	0	-	0	-	ns
C _{PD}	power dissipation	$ f_i = 1 \text{ MHz}; $ [3] $V_I = \text{GND to } V_{\text{CC}} $								_
	capacitance	V _{CC} = 0.8 V	-	1.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	1.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	1.8	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	1.9	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	2.2	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	2.7	-	-	-	-	-	pF

[1] All typical values are measured at nominal $V_{\mbox{CC}}.$

[2]

[3]

All typical values are measured at nominal V_{CC}. t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in µW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.



11.1. Waveforms and test circuit

Fig. 8. The master reset (MR) input to output (Q) propagation delays, the master reset pulse width and the MR to CP recovery time

Table 9. Measurement points

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	t _r = t _f
0.8 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns

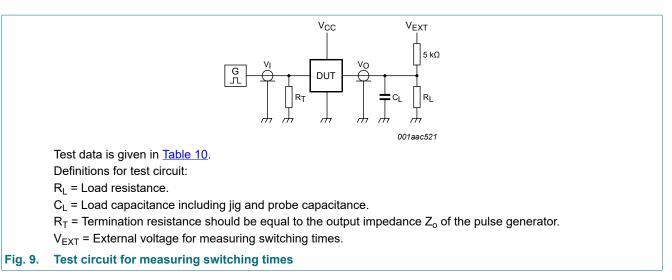


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline

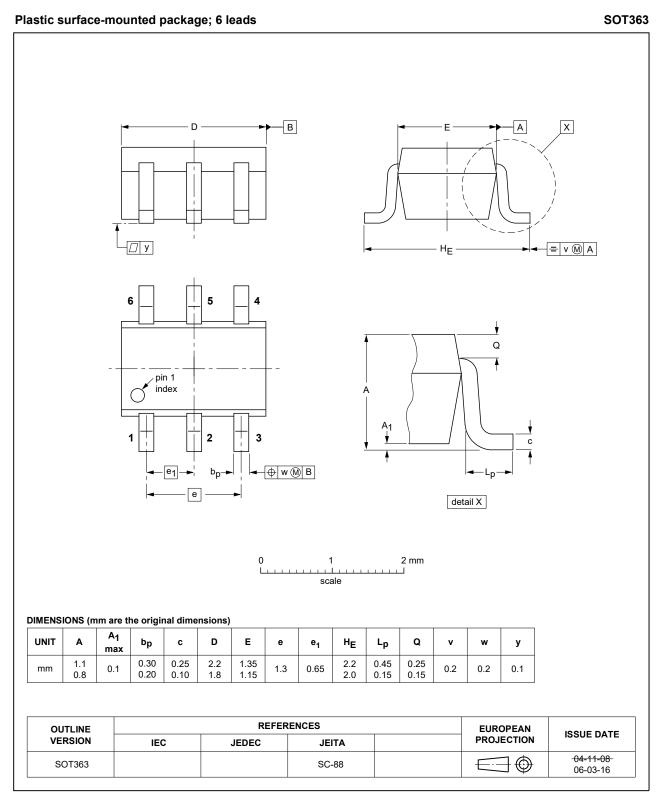


Fig. 10. Package outline SOT363 (SC-88)

Low-power D-type flip-flop with reset; positive-edge trigger

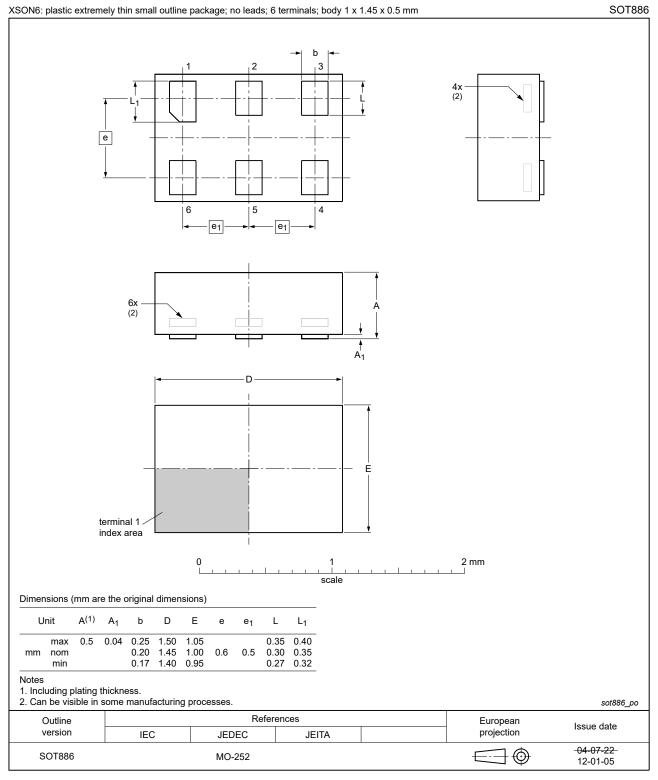


Fig. 11. Package outline SOT886 (XSON6)

XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

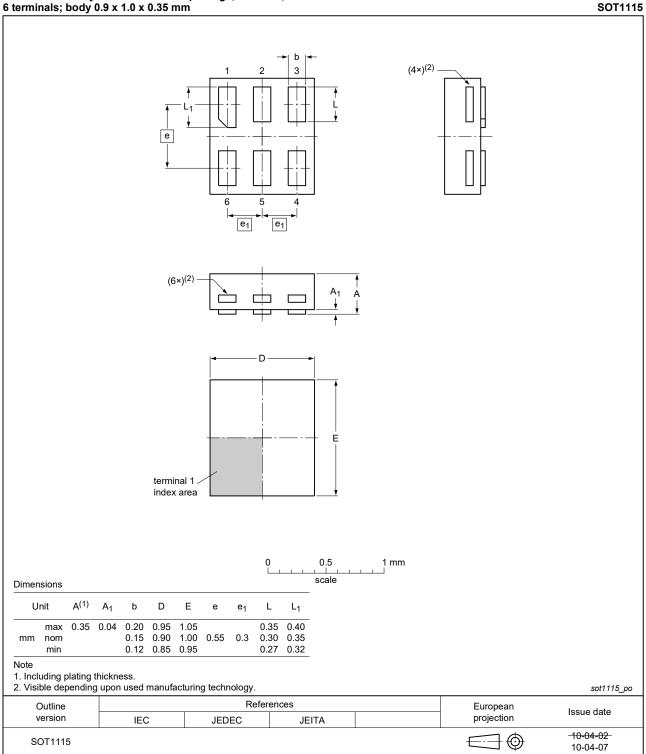
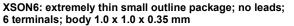


Fig. 12. Package outline SOT1115 (XSON6)

Low-power D-type flip-flop with reset; positive-edge trigger



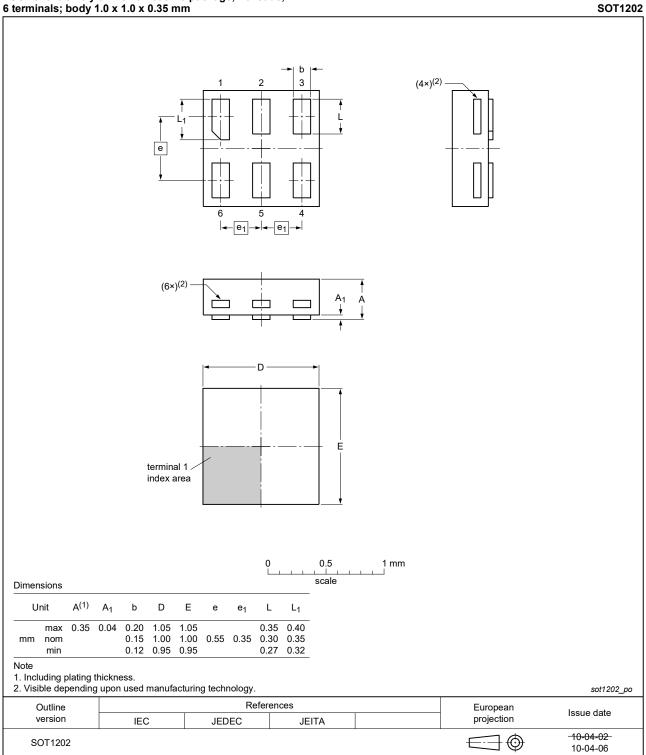


Fig. 13. Package outline SOT1202 (XSON6)

13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 12. Revision his	story								
Document ID	Release date	Data sheet status	Change notice	Supersedes					
74AUP1G175 v.6	20210402	Product data sheet	-	74AUP1G175 v.5					
Modifications:	Nexperia. Legal texts hat <u>Section 8</u>: De 	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. <u>Section 8</u>: Derating values for P_{tot} total power dissipation updated. Type number 74AUP1G175GF (SOT891/XSON6) removed. 							
74AUP1G175 v.5	20120703	Product data sheet	-	74AUP1G175 v.4					
Modifications:	Package outli	ne drawing of SOT886 (Fig	<u>g. 11</u>) modified.	'					
74AUP1G175 v.4	20111124	Product data sheet	-	74AUP1G175 v.3					
Modifications:	• Legal pages u	updated.	I						
74AUP1G175 v.3	20100930	Product data sheet	-	74AUP1G175 v.2					
74AUP1G175 v.2	20080228	Product data sheet	-	74AUP1G175 v.1					
74AUP1G175 v.1	20061115	Product data sheet	-	-					

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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